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Development of Deep-Ultraviolet Solid-State Lasers for Raman Spectroscopy

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Program: (Low Allen, Strategic Initiative, Topic, Spontaneous Concept, or SURP)

Assigned Presentation # R20101



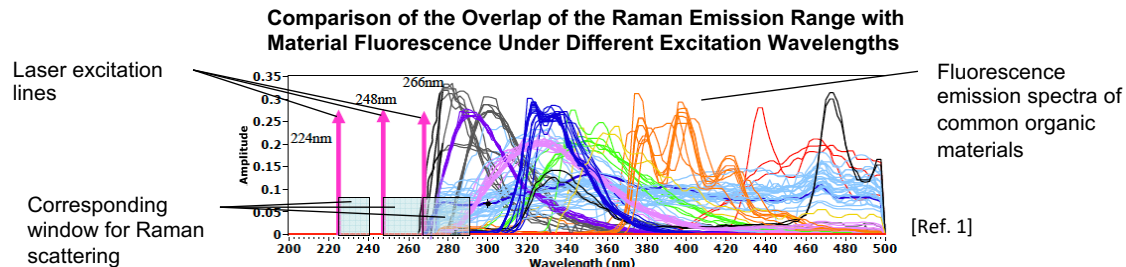
Jet Propulsion Laboratory
California Institute of Technology

Tutorial Introduction



Abstract

Spectroscopic analysis techniques such as Raman spectroscopy and luminescence measurements benefit immensely from the utilization of deep-ultraviolet coherent light sources. Deep-ultraviolet excitation provides multiple benefits which collectively contribute to an enhanced detection capability, for biosignatures and other species of interest. The current work aims to develop a solid-state platform for the generation of coherent deep-ultraviolet light. The technology concept relies on borate-based nonlinear optical crystal layers, which feature a broad transparency window and are capable of frequency upconversion into the deep-ultraviolet range. The implemented platform utilizes integrated photonic components to fulfill phase matching and additionally enhance the conversion efficiency of the device.



Problem Description

a) Context

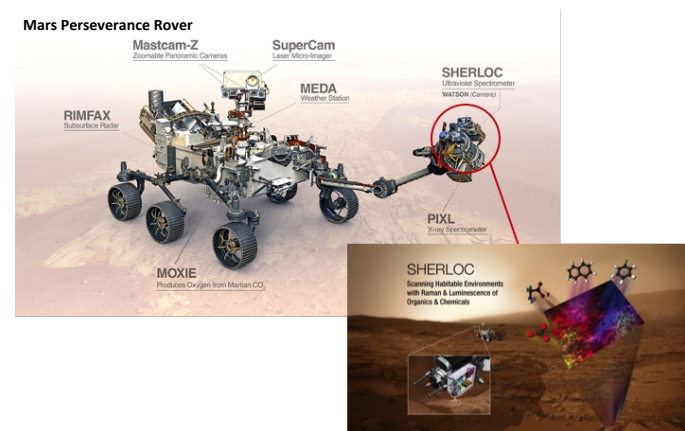
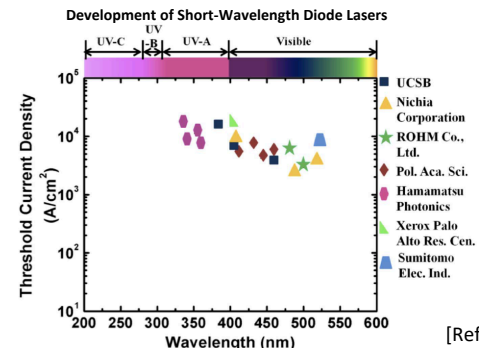
- Compact deep-ultraviolet (deep-UV) coherent light sources are required for spectroscopic analysis on planetary exploration missions
- State-of-the-art technology for coherent deep-UV sources faces technical hurdles, resulting in devices with limited performance and reliability

b) Comparison with State-of-the-Art

Criterion	State-of-the-Art NeCu Gas Laser	Proposed Solid-State Laser
Mass	470 g	~100 g
Power Output	~40 μ s of <20 μ W @80 Hz, pulsed	>1 mW, continuous-wave
Volume/Size	~500 cm ³ / ~5 cm diameter, 25 cm length	<250 cm ³ / ~1 cm ² chip area
Emission Wavelength	248.6 \pm 0.05 nm (fixed)	Any wavelength down to 225 nm
Beam Quality (M ²)	>30	\approx 1.1 (near diffraction limit)
Robustness	Gas tube	Solid-state components
Spot Size	~100 microns	<3 microns

c) Relevance to NASA and JPL

- Raman spectroscopy and luminescence spectroscopy instruments are essential tools for life detection and assessment of habitability
- The developed technology will contribute to planetary instruments carried on upcoming exploratory missions, which will require reliable and robust devices



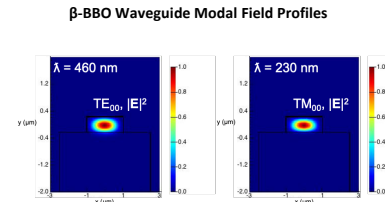
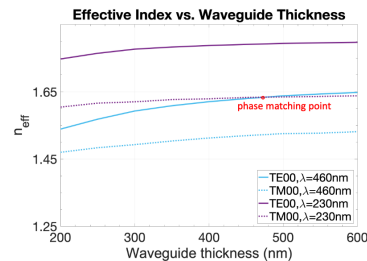
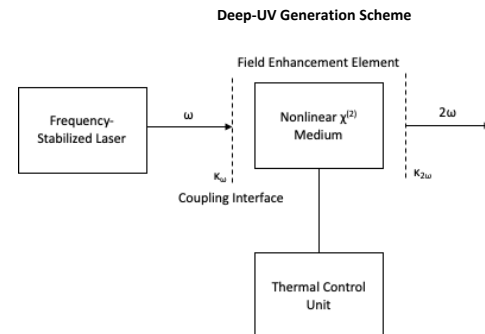
Methodology

a) Formulation

- a) Raman spectroscopy and other spectroscopic techniques benefit greatly from deep-UV sources
- b) Deep-UV generation can be generated in nonlinear media with short-wavelength transparency combined with suitable dispersion properties
- c) Cladded optical-grade β -barium borate (β -BBO) layers enable the fabrication of integrated photonic elements
- d) Phase-matching in nonlinear waveguides is required for efficient nonlinear frequency conversion

b) Innovation / Advancement

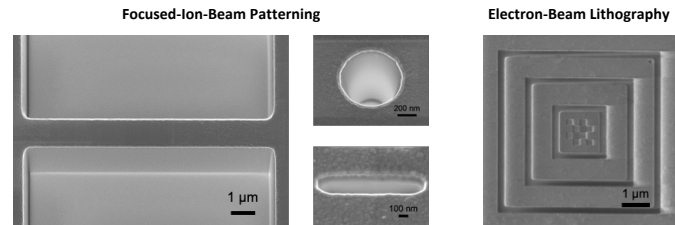
- a) A novel thin-layer β -BBO-on-insulator platform supports nonlinear optical processes spanning the near-infrared to deep-ultraviolet range
- b) Phase matching can be precisely engineered using integrated photonic elements
- c) Compact, high-power semiconductor light sources can be incorporated as optical pumps



Results

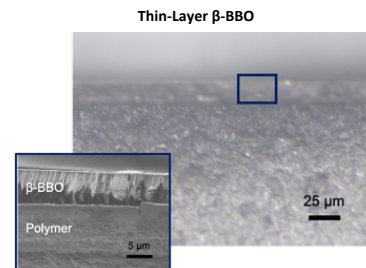
a) Goals and accomplishments

- a) Development of designs for nonlinear frequency conversion
 - Phase-matched β -BBO nonlinear waveguides designed
- b) Demonstration of patterning in free-standing β -BBO crystal
 - High-aspect ratio ($> 5:1$) patterning of β -BBO crystal demonstrated using focused-ion-beam milling
 - Anhydrous electron-beam lithographic patterning of β -BBO implemented and is in the optimization phase
- c) Thin-layer development for β -BBO
 - Initial implementation of thin β -BBO layers ($5\ \mu\text{m}$ -thickness) using optical-grade polymer cladding, currently being transitioned to silica cladding
- d) Implementation of a measurement testbed
 - Measurement setup has been implemented for the characterization of visible-to-deep-UV integrated photonic chips



Micro/nanoscale features directly milled in free-standing β -BBO crystals.

Patterned chromium hard mask on β -BBO free-standing crystal through anhydrous processing.



Cross-sectional brightfield microscopy image of thin layer β -BBO, and the corresponding scanning electron microscopy close-up in the inset. The cross-sectional cut was prepared by dicing.

Results

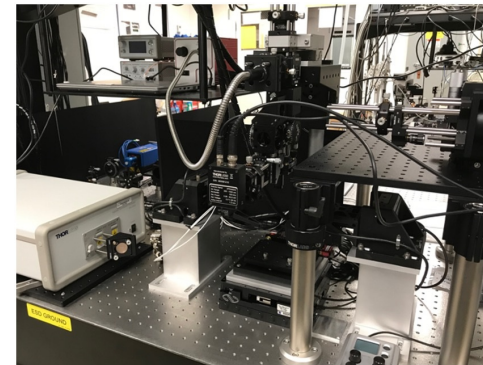
a) Significance

- a) Existing nonlinear optical layers do not operate in the short-visible to deep-UV wavelength range
- b) A mature micro-/nano-scale fabrication process for β -BBO has not been developed yet
- c) This technology development is unique and complements the UV detection competency at the Microdevices Laboratory

b) Next steps

- a) Optimization of the fabrication process
- b) Fabricating and testing the designed photonic chips to target propagation losses below 5 dBcm^{-1} in β -BBO waveguides at the pump wavelength

Measurement Testbed at the Microdevices Laboratory



Publications and References

Publications:

New Technology Report # 51684, “Method for the Preparation of Thin-Layer Beta-Barium Borate”

References:

- [1] W. F. Hug et al., Chemical and Biological Sensors for Industrial and Environmental Monitoring II 6378, 63780S (2006).
- [2] S. Zhao and Z. Mi, IEEE J. Quantum Electron. 54, 1-9 (2018).

Acknowledgements

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